

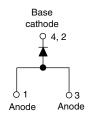
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High Performance Schottky Rectifier, 5.5 A

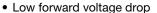


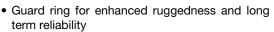
D-PAK (TO-252AA)



PRODUCT SUMMARY				
Package	D-PAK (TO-252AA)			
I _{F(AV)}	5.5 A			
V_{R}	30 V			
V _F at I _F	See Electrical table			
I _{RM}	58 mA at 125 °C			
T _J max.	150 °C			
Diode variation	Single die			
E _{AS}	10 mJ			

FEATURES







FREE

- Popular D-PAK outline
- · Small foot print, surface mountable
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The VS-50WQ03FN-M3 surface mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I _{F(AV)}	Rectangular waveform	5.5	А			
V _{RRM}		30	V			
I _{FSM}	t _p = 5 μs sine	320	Α			
V _F	5 A _{pk} , T _J = 125 °C	0.35	V			
TJ	Range	-40 to +150	°C			

VOLTAGE RATINGS						
PARAMETER SYMBOL VS-50WQ03FN-M3 UNITS						
Maximum DC reverse voltage	V_{R}	30	V			
Maximum working peak reverse voltage	V_{RWM}	30	V			

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDI	VALUES	UNITS		
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T _C = 136 °C	5.5	А		
Maximum peak one cycle non-repetitive surge current	I _{FSM}	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with	320	A	
See fig. 7		10 ms sine or 6 ms rect. pulse	rated V _{RRM} applied	130		
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 2 A, L = 5 mH		10	mJ	
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T_J maximum $V_A = 1.5 \times V_R$ typical		2.0	Α	



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ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS		
		5 A	T _{.1} = 25 °C	0.46	V	
Maximum forward voltage drop	V _{FM} ⁽¹⁾	10 A	11 = 23 0	0.53		
See fig. 1	V FM ('')	5 A	T _{.1} = 125 °C	0.35		
		10 A	1j=125 C	0.46		
Maximum reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C	V _B = Rated V _B	3	A	
See fig. 2	IRM (*)	T _J = 125 °C	VR = nateu VR	58	- mA	
Threshold voltage	V _{F(TO)}	T - T movimum		0.19	V	
Forward slope resistance	r _t	$T_J = T_J$ maximum		22.22	mΩ	
Typical junction capacitance	C _T	V _R = 5 V _{DC} (test signal ran	590	pF		
Typical series inductance	L _S	Measured lead to lead 5 r	Measured lead to lead 5 mm from package body			

Note

 $^{^{(1)}\,}$ Pulse width $<300~\mu s,$ duty cycle <2~%

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range	T _J ⁽¹⁾ , T _{Stg}		-40 to +150	°C	
Maximum thermal resistance, junction to case	R _{thJC}	DC operation See fig. 4	3.0	°C/W	
Approximate weight			0.3	g	
Approximate weight			0.01	oz.	
Marking device		Case style D-PAK (similar to TO-252AA)	50WC	03FN	

Note

(1)
$$\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$$
 thermal runaway condition for a diode on its own heatsink

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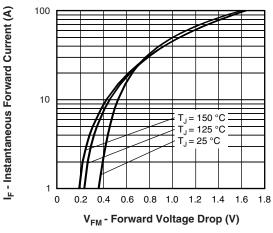


Fig. 1 - Maximum Forward Voltage Drop Characteristics

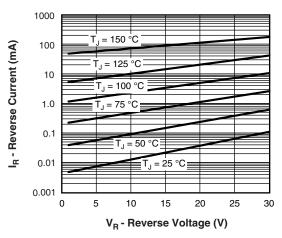


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

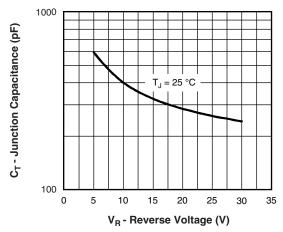


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

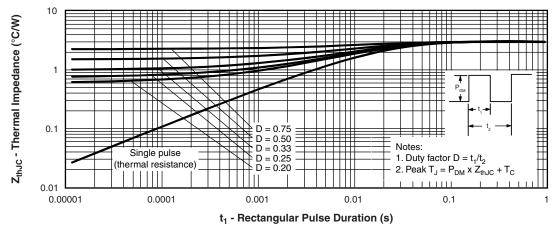


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics



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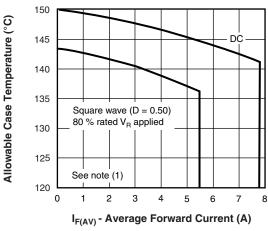


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

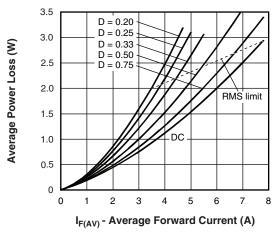


Fig. 6 - Forward Power Loss Characteristics

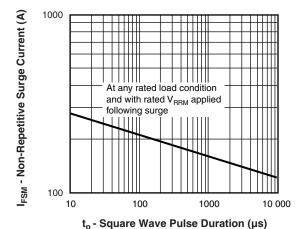


Fig. 7 - Maximum Non-Repetitive Surge Current

Note

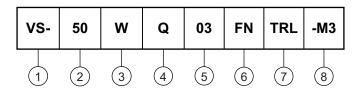
 $^{(1)}$ Formula used: T_C = T_J - (Pd + Pd_{REV}) x R_{thJC}; Pd = forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = 80 % rated V_R



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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (5.5 A)

Package identifier:

W = D-PAK

4 - Schottky "Q" series

Voltage rating (03 = 30 V)

- FN = TO-252AA (D-PAK)

7 - • None = tube

• TR = tape and reel

• TRL = tape and reel (left oriented)

• TRR = tape and reel (right oriented)

8 - Environmental digit:

-M3 = halogen-free, RoHS-compliant and terminations lead (Pb)-free

ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-50WQ03FN-M3	75	3000	Antistatic plastic tube			
VS-50WQ03FNTR-M3	2000	2000	13" diameter reel			
VS-50WQ03FNTRL-M3	3000	3000	13" diameter reel			
VS-50WQ03FNTRR-M3	3000	3000	13" diameter reel			

LINKS TO RELATED DOCUMENTS				
Dimensions <u>www.vishay.com/doc?95627</u>				
Part marking information <u>www.vishay.com/doc?95176</u>				
Packaging information	www.vishay.com/doc?95033			



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D-PAK (TO-252AA) "M"

DIMENSIONS in millimeters and inches



SYMBOL MILLIMETERS INCHES		HES	NOTES		
STWIDGE	MIN.	MAX.	MIN.	MAX.	NOTES
Α	2.18	2.39	0.086	0.094	
A1	-	0.13	-	0.005	
b	0.64	0.89	0.025	0.035	
b2	0.76	1.14	0.030	0.045	
b3	4.95	5.46	0.195	0.215	3
С	0.46	0.61	0.018	0.024	
c2	0.46	0.89	0.018	0.035	
D	5.97	6.22	0.235	0.245	5
D1	5.21	-	0.205	1	3
Е	6.35	6.73	0.250	0.265	5
E1	4.32	-	0.170	-	3

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
OTIMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
е	2.29 BSC		0.090	BSC	
Н	9.40	10.41	0.370	0.410	
L	1.40	1.78	0.055	0.070	
L1	2.74 BSC		0.108 REF.		
L2	0.51	BSC	0.020	BSC	
L3	0.89	1.27	0.035	0.050	3
L4	-	1.02	-	0.040	
L5	1.14	1.52	0.045	0.060	2
Ø	0°	10°	0°	10°	
Ø1	0°	15°	0°	15°	
Ø2	25°	35°	25°	35°	

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension uncontrolled in L5
- (3) Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad
- (4) Section C C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip
- (5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (6) Dimension b1 and c1 applied to base metal only
- (7) Datum A and B to be determined at datum plane H
- (8) Outline conforms to JEDEC® outline TO-252AA



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